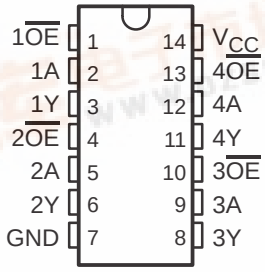
# SN54HC125, SN74HC125
# QUADRUPLE BUS BUFFER GATES WITH 3-STATE OUTPUTS

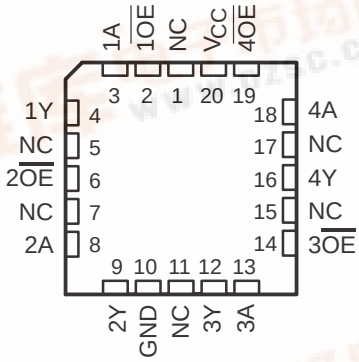
SCLS104B – MARCH 1984 – REVISED MAY 1997

- **High-Current 3-State Outputs Interface Directly With System Bus or Can Drive up to 15 LSTTL Loads**
- **Package Options Include Plastic Small-Outline (D), Shrink Small-Outline (DB), and Ceramic Flat (W) Packages, Ceramic Chip Carriers (FK), and Standard Plastic (N) and Ceramic (J) 300-mil DIPs**

**SN54HC125 . . . J OR W PACKAGE**
**SN74HC125 . . . D, DB, OR N PACKAGE**
**(TOP VIEW)**




**SN54HC125 . . . FK PACKAGE**
**(TOP VIEW)**




NC – No internal connection

## description

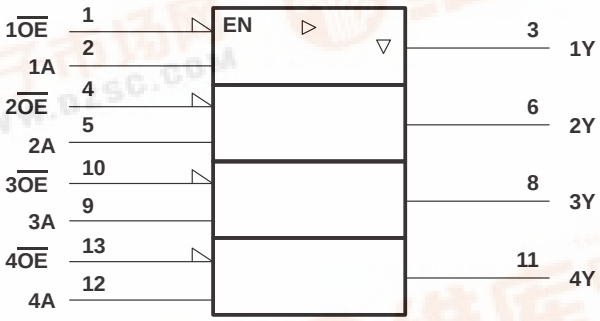
These quadruple bus buffer gates feature independent line drivers with 3-state outputs. Each output is disabled when the associated output-enable ($\overline{OE}$) input is high.

The SN54HC125 is characterized for operation over the full military temperature range of –55°C to 125°C. The SN74HC125 is characterized for operation from –40°C to 85°C.

**FUNCTION TABLE**
**(each buffer)**

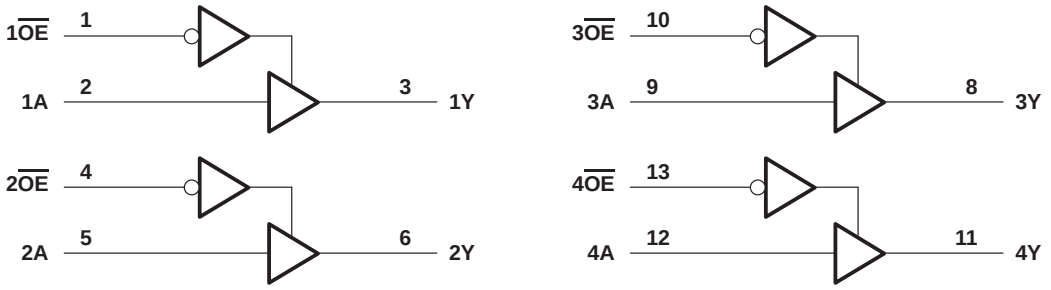
| INPUTS | | OUTPUT |
|---|---|---|
| $\overline{OE}$ | A | Y |
| L | H | H |
| L | L | L |
| H | X | Z |

## logic symbol†




† This symbol is in accordance with ANSI/IEEE Std 91-1984 and IEC Publication 617-12.
Pin numbers shown are for the D, DB, J, N, and W packages.

## logic diagram (positive logic)




Pin numbers shown are for the D, DB, J, N, and W packages.

## absolute maximum ratings over operating free-air temperature range†

Supply voltage range, $V_{CC}$ . . . . . –0.5 V to 7 V
Input clamp current, $I_{IK}$ ($V_I < 0$ or $V_I > V_{CC}$) (see Note 1) . . . . . ±20 mA
Output clamp current, $I_{OK}$ ($V_O < 0$ or $V_O > V_{CC}$) (see Note 1) . . . . . ±20 mA
Continuous output current, $I_O$ ($V_O$ = 0 to $V_{CC}$) . . . . . ±35 mA
Continuous current through $V_{CC}$ or GND . . . . . ±70 mA
Package thermal impedance, $\theta_{JA}$ (see Note 2): D package . . . . . 127°C/W
DB package . . . . . 158°C/W
N package . . . . . 78°C/W
Storage temperature range, $T_{stg}$ . . . . . –65°C to 150°C

† Stresses beyond those listed under “absolute maximum ratings” may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under “recommended operating conditions” is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

NOTES: 1. The input and output voltage ratings may be exceeded if the input and output current ratings are observed.
2. The package thermal impedance is calculated in accordance with JESD 51, except for through-hole packages, which use a trace length of zero.

## recommended operating conditions

| | | | SN54HC125 | | | SN74HC125 | | | UNIT |
|---|---|---|---|---|---|---|---|---|---|
| | | | MIN | NOM | MAX | MIN | NOM | MAX | |
| $V_{CC}$ | Supply voltage | | 2 | 5 | 6 | 2 | 5 | 6 | V |
| $V_{IH}$ | High-level input voltage | $V_{CC}$ = 2 V | 1.5 | | | 1.5 | | | V |
| | | $V_{CC}$ = 4.5 V | 3.15 | | | 3.15 | | | |
| | | $V_{CC}$ = 6 V | 4.2 | | | 4.2 | | | |
| $V_{IL}$ | Low-level input voltage | $V_{CC}$ = 2 V | 0 | | 0.5 | 0 | | 0.5 | V |
| | | $V_{CC}$ = 4.5 V | 0 | | 1.35 | 0 | | 1.35 | |
| | | $V_{CC}$ = 6 V | 0 | | 1.8 | 0 | | 1.8 | |
| $V_I$ | Input voltage | | 0 | | $V_{CC}$ | 0 | | $V_{CC}$ | V |
| $V_O$ | Output voltage | | 0 | | $V_{CC}$ | 0 | | $V_{CC}$ | V |
| $t_t$ | Input transition (rise and fall) time | $V_{CC}$ = 2 V | 0 | | 1000 | 0 | | 1000 | ns |
| | | $V_{CC}$ = 4.5 V | 0 | | 500 | 0 | | 500 | |
| | | $V_{CC}$ = 6 V | 0 | | 400 | 0 | | 400 | |
| $T_A$ | Operating free-air temperature | | –55 | | 125 | –40 | | 85 | °C |

**electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)**

| PARAMETER | TEST CONDITIONS | | $V_{CC}$ | $T_A$ = 25°C | | | SN54HC125 | | SN74HC125 | | UNIT |
|---|---|---|---|---|---|---|---|---|---|---|---|
| | | | | MIN | TYP | MAX | MIN | MAX | MIN | MAX | |
| $V_{OH}$ | $V_I = V_{IH}$ or $V_{IL}$ | $I_{OH}$ = –20 µA | 2 V | 1.9 | 1.998 | | 1.9 | | 1.9 | | V |
| | | | 4.5 V | 4.4 | 4.499 | | 4.4 | | 4.4 | | |
| | | | 6 V | 5.9 | 5.999 | | 5.9 | | 5.9 | | |
| | | $I_{OH}$ = –6 mA | 4.5 V | 3.98 | 4.3 | | 3.7 | | 3.84 | | |
| | | $I_{OH}$ = –7.8 mA | 6 V | 5.48 | 5.8 | | 5.2 | | 5.34 | | |
| $V_{OL}$ | $V_I = V_{IH}$ or $V_{IL}$ | $I_{OL}$ = 20 µA | 2 V | | 0.002 | 0.1 | | 0.1 | | 0.1 | V |
| | | | 4.5 V | | 0.001 | 0.1 | | 0.1 | | 0.1 | |
| | | | 6 V | | 0.001 | 0.1 | | 0.1 | | 0.1 | |
| | | $I_{OL}$ = 6 mA | 4.5 V | | 0.17 | 0.26 | | 0.4 | | 0.33 | |
| | | $I_{OL}$ = 7.8 mA | 6 V | | 0.15 | 0.26 | | 0.4 | | 0.33 | |
| $I_I$ | $V_I = V_{CC}$ or 0 | | 6 V | | | ±0.1 | ±100 | | ±1000 | | ±1000 | nA |
| $I_{OZ}$ | $V_O = V_{CC}$ or 0 | | 6 V | | | ±0.01 | ±0.5 | | ±10 | | ±5 | µA |
| $I_{CC}$ | $V_I = V_{CC}$ or 0, | $I_O$ = 0 | 6 V | | | 8 | | 160 | | 80 | µA |
| $C_i$ | | | 2 V to 6 V | | 3 | 10 | | 10 | | 10 | pF |

**switching characteristics over recommended operating free-air temperature range, $C_L$ = 50 pF (unless otherwise noted) (see Figure 1)**

| PARAMETER | FROM (INPUT) | TO (OUTPUT) | $V_{CC}$ | $T_A$ = 25°C | | | SN54HC125 | | SN74HC125 | | UNIT |
|---|---|---|---|---|---|---|---|---|---|---|---|
| | | | | MIN | TYP | MAX | MIN | MAX | MIN | MAX | |
| $t_{pd}$ | A | Y | 2 V | | 48 | 120 | | 150 | | 150 | ns |
| | | | 4.5 V | | 14 | 24 | | 36 | | 30 | |
| | | | 6 V | | 11 | 20 | | 25 | | 26 | |
| $t_{en}$ | $\overline{OE}$ | Y | 2 V | | 53 | 120 | | 180 | | 150 | ns |
| | | | 4.5 V | | 14 | 24 | | 36 | | 30 | |
| | | | 6 V | | 11 | 20 | | 31 | | 26 | |
| $t_{dis}$ | $\overline{OE}$ | Y | 2 V | | 30 | 120 | | 180 | | 150 | ns |
| | | | 4.5 V | | 15 | 24 | | 36 | | 30 | |
| | | | 6 V | | 14 | 20 | | 31 | | 26 | |
| $t_t$ | | Any | 2 V | | 28 | 60 | | 90 | | 75 | ns |
| | | | 4.5 V | | 8 | 12 | | 18 | | 15 | |
| | | | 6 V | | 6 | 10 | | 15 | | 13 | |

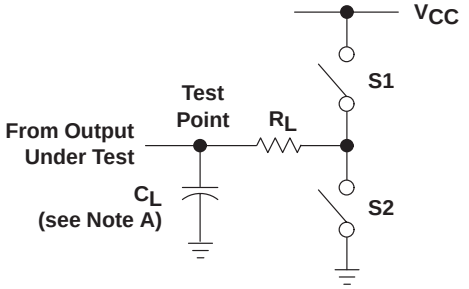
### switching characteristics over recommended operating free-air temperature range, $C_L$ = 150 pF (unless otherwise noted) (see Figure 1)

| PARAMETER | FROM (INPUT) | TO (OUTPUT) | $V_{CC}$ | $T_A$ = 25°C | | | SN54HC125 | | SN74HC125 | | UNIT |
|---|---|---|---|---|---|---|---|---|---|---|---|
| | | | | MIN | TYP | MAX | MIN | MAX | MIN | MAX | |
| $t_{pd}$ | A | Y | 2 V | | 67 | 150 | | 225 | | 190 | ns |
| | | | 4.5 V | | 19 | 30 | | 45 | | 38 | |
| | | | 6 V | | 15 | 25 | | 39 | | 32 | |
| $t_{en}$ | $\overline{OE}$ | Y | 2 V | | 100 | 135 | | 200 | | 170 | ns |
| | | | 4.5 V | | 20 | 27 | | 40 | | 34 | |
| | | | 6 V | | 17 | 23 | | 34 | | 29 | |
| $t_t$ | | Any | 2 V | | 45 | 210 | | 315 | | 265 | ns |
| | | | 4.5 V | | 17 | 42 | | 63 | | 53 | |
| | | | 6 V | | 13 | 36 | | 53 | | 45 | |

### operating characteristics, $T_A$ = 25°C

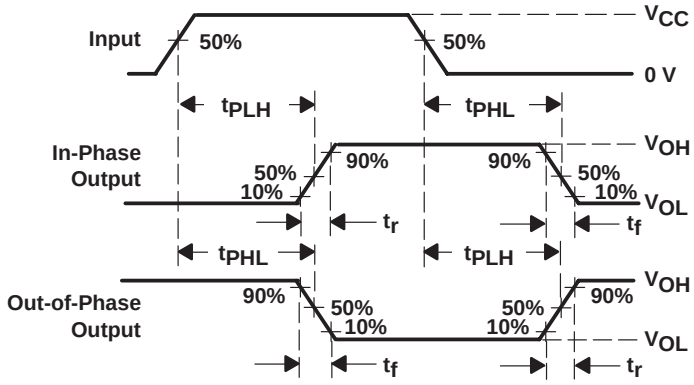
| PARAMETER | | TEST CONDITIONS | TYP | UNIT |
|---|---|---|---|---|
| $C_{pd}$ | Power dissipation capacitance per gate | No load | 45 | pF |

## PARAMETER MEASUREMENT INFORMATION

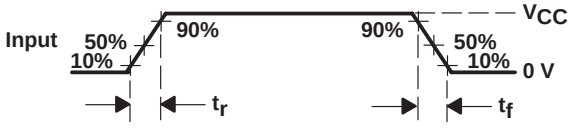



LOAD CIRCUIT

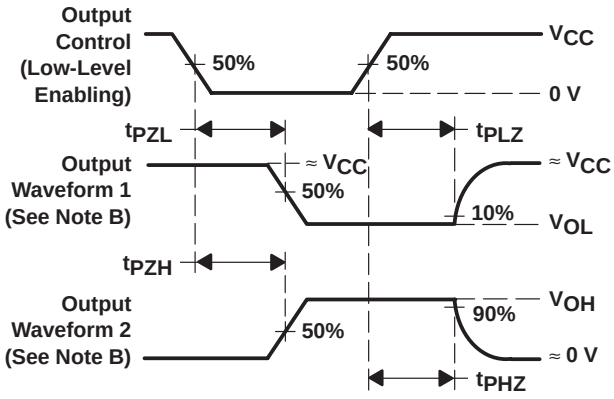
| PARAMETER | | $R_L$ | $C_L$ | S1 | S2 |
|---|---|---|---|---|---|
| $t_{en}$ | $t_{PZH}$ | 1 kΩ | 50 pF or 150 pF | Open | Closed |
| | $t_{PZL}$ | | | Closed | Open |
| $t_{dis}$ | $t_{PHZ}$ | 1 kΩ | 50 pF | Open | Closed |
| | $t_{PLZ}$ | | | Closed | Open |
| $t_{pd}$ or $t_t$ | | –– | 50 pF or 150 pF | Open | Open |




VOLTAGE WAVEFORMS
PROPAGATION DELAY AND OUTPUT TRANSITION TIMES




VOLTAGE WAVEFORM
INPUT RISE AND FALL TIMES




VOLTAGE WAVEFORMS
ENABLE AND DISABLE TIMES FOR 3-STATE OUTPUTS

NOTES: A. $C_L$ includes probe and test-fixture capacitance.
B. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.
C. Phase relationships between waveforms were chosen arbitrarily. All input pulses are supplied by generators having the following characteristics: PRR ≤ 1 MHz, $Z_O$ = 50 Ω, $t_r$ = 6 ns, $t_f$ = 6 ns.
D. The outputs are measured one at a time with one input transition per measurement.
E. $t_{PLZ}$ and $t_{PHZ}$ are the same as $t_{dis}$.
F. $t_{PZL}$ and $t_{PZH}$ are the same as $t_{en}$.
G. $t_{PLH}$ and $t_{PHL}$ are the same as $t_{pd}$.

**Figure 1. Load Circuit and Voltage Waveforms**

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